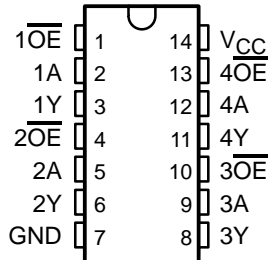


SN54AHC125, SN74AHC125 QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

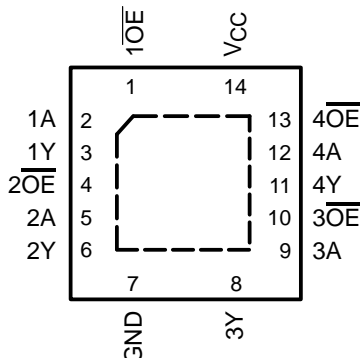
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- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17

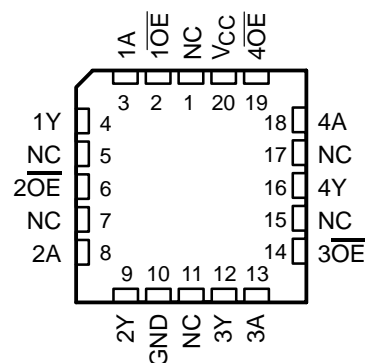
SN54AHC125 . . . J OR W PACKAGE
SN74AHC125 . . . D, DB, DGV, N, NS,
OR PW PACKAGE
(TOP VIEW)



SN74AHC125 . . . RGY PACKAGE
(TOP VIEW)



SN54AHC125 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

description/ordering information

The 'AHC125 devices are quadruple bus buffer gates featuring independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable (\overline{OE}) input is high. When \overline{OE} is low, the respective gate passes the data from the A input to its Y output.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RGY	Tape and reel	SN74AHC125RGYR	HA125
	PDIP – N	Tube	SN74AHC125N	SN74AHC125N
	SOIC – D	Tube	SN74AHC125D	AHC125
		Tape and reel	SN74AHC125DR	
	SOP – NS	Tape and reel	SN74AHC125NSR	AHC125
	SSOP – DB	Tape and reel	SN74AHC125DBR	HA125
	TSSOP – PW	Tape and reel	SN74AHC125PWR	HA125
–55°C to 125°C	TVSOP – DGV	Tape and reel	SN74AHC125DGV	HA125
	CDIP – J	Tube	SNJ54AHC125J	SNJ54AHC125J
	CFP – W	Tube	SNJ54AHC125W	SNJ54AHC125W
	LCCC – FK	Tube	SNJ54AHC125FK	SNJ54AHC125FK

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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SN54AHC125, SN74AHC125

QUADRUPLE BUS BUFFER GATES

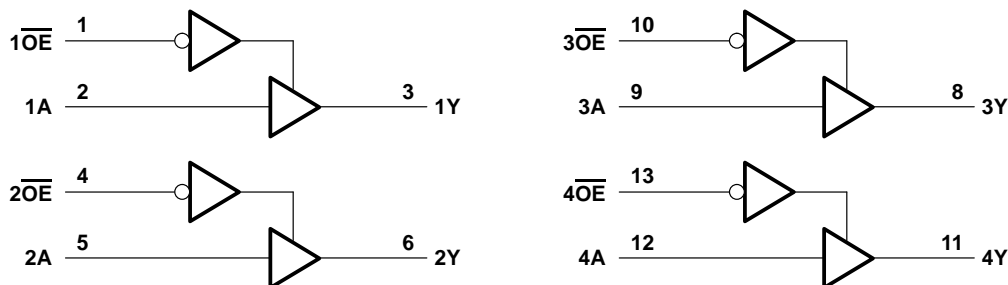
WITH 3-STATE OUTPUTS

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FUNCTION TABLE
(each buffer)

INPUTS		OUTPUT
\overline{OE}	A	Y
L	H	H
L	L	L
H	X	Z

logic diagram (positive logic)



Pin numbers shown are for the D, DB, DGV, J, N, NS, PW, RGY, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Output voltage range, V_O (see Note 1)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	–20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V_{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): D package	86°C/W
(see Note 2): DB package	96°C/W
(see Note 2): DGV package	127°C/W
(see Note 2): N package	80°C/W
(see Note 2): NS package	76°C/W
(see Note 2): PW package	113°C/W
(see Note 3): RGY package	47°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51-7.
3. The package thermal impedance is calculated in accordance with JESD 51-5.

SN54AHC125, SN74AHC125 QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

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recommended operating conditions (see Note 4)

			SN54AHC125		SN74AHC125		UNIT
			MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage		2	5.5	2	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 2 V	1.5		1.5		V
		V _{CC} = 3 V	2.1		2.1		
		V _{CC} = 5.5 V	3.85		3.85		
V _{IL}	Low-level input voltage	V _{CC} = 2 V		0.5		0.5	V
		V _{CC} = 3 V		0.9		0.9	
		V _{CC} = 5.5 V		1.65		1.65	
V _I	Input voltage		0	5.5	0	5.5	V
V _O	Output voltage		0	V _{CC}	0	V _{CC}	V
I _{OH}	High-level output current	V _{CC} = 2 V		–50		–50	μA
		V _{CC} = 3.3 V ± 0.3 V		–4		–4	mA
		V _{CC} = 5 V ± 0.5 V		–8		–8	
I _{OL}	Low-level output current	V _{CC} = 2 V		50		50	μA
		V _{CC} = 3.3 V ± 0.3 V		4		4	mA
		V _{CC} = 5 V ± 0.5 V		8		8	
Δt/Δv	Input transition rise or fall rate	V _{CC} = 3.3 V ± 0.3 V		100		100	ns/V
		V _{CC} = 5 V ± 0.5 V		20		20	
T _A	Operating free-air temperature		–55	125	–40	85	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			SN54AHC125		SN74AHC125		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V _{OH}	I _{OH} = –50 μA	2 V	1.9	2		1.9		1.9		V
		3 V	2.9	3		2.9		2.9		
		4.5 V	4.4	4.5		4.4		4.4		
	I _{OH} = –4 mA	3 V	2.58			2.48		2.48		
	I _{OH} = –8 mA	4.5 V	3.94			3.8		3.8		
V _{OL}	I _{OL} = 50 μA	2 V			0.1		0.1		0.1	V
		3 V			0.1		0.1		0.1	
		4.5 V			0.1		0.1		0.1	
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
I _I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1*		±1	μA
I _{OZ}	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5		±2.5	μA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V			4		40		40	μA
C _i	V _I = V _{CC} or GND	5 V		4	10				10	pF

* On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.



SN54AHC125, SN74AHC125

QUADRUPLE BUS BUFFER GATES

WITH 3-STATE OUTPUTS

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switching characteristics over recommended operating free-air temperature range,
 $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN54AHC125		SN74AHC125		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A	Y	C _L = 15 pF	5.6*	8*	1*	9.5*	1	9.5	ns	
t _{PHL}				5.6*	8*	1*	9.5*	1	9.5		
t _{PZH}	OE	Y	C _L = 15 pF	5.4*	8*	1*	9.5*	1	9.5	ns	
t _{PZL}				5.4*	8*	1*	9.5*	1	9.5		
t _{PHZ}	OE	Y	C _L = 15 pF	7*	9.7*	1*	11.5*	1	11.5	ns	
t _{PLZ}				7*	9.7*	1*	11.5*	1	11.5		
t _{PLH}	A	Y	C _L = 50 pF	8.1	11.5	1	13	1	13	ns	
t _{PHL}				8.1	11.5	1	13	1	13		
t _{PZH}	OE	Y	C _L = 50 pF	7.9	11.5	1	13	1	13	ns	
t _{PZL}				7.9	11.5	1	13	1	13		
t _{PHZ}	OE	Y	C _L = 50 pF	9.5	13.2	1	15	1	15	ns	
t _{PLZ}				9.5	13.2	1	15	1	15		
t _{sk(o)}	OE	Y	C _L = 50 pF	1.5**				1.5		ns	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

** On products compliant to MIL-PRF-38535, this parameter does not apply.

switching characteristics over recommended operating free-air temperature range,
 $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN54AHC125		SN74AHC125		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A	Y	C _L = 15 pF	3.8*	5.5*	1*	6.5*	1	6.5	ns	
t _{PHL}				3.8*	5.5*	1*	6.5*	1	6.5		
t _{PZH}	\overline{OE}	Y	C _L = 15 pF	3.6*	5.1*	1*	6*	1	6	ns	
t _{PZL}				3.6*	5.1*	1*	6*	1	6		
t _{PHZ}	\overline{OE}	Y	C _L = 15 pF	4.6*	6.8*	1*	8*	1	8	ns	
t _{PLZ}				4.6*	6.8*	1*	8*	1	8		
t _{PLH}	A	Y	C _L = 50 pF	5.3	7.5	1	8.5	1	8.5	ns	
t _{PHL}				5.3	7.5	1	8.5	1	8.5		
t _{PZH}	\overline{OE}	Y	C _L = 50 pF	5.1	7.1	1	8	1	8	ns	
t _{PZL}				5.1	7.1	1	8	1	8		
t _{PHZ}	\overline{OE}	Y	C _L = 50 pF	6.1	8.8	1	10	1	10	ns	
t _{PLZ}				6.1	8.8	1	10	1	10		
t _{sk(o)}			C _L = 50 pF	1**				1		ns	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

** On products compliant to MIL-PRF-38535, this parameter does not apply.



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SN54AHC125, SN74AHC125
QUADRUPLER BUS BUFFER GATES
WITH 3-STATE OUTPUTS

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noise characteristics, $V_{CC} = 5\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ (see Note 5)

PARAMETER	SN74AHC125		UNIT
	MIN	MAX	
$V_{OL(P)}$ Quiet output, maximum dynamic V_{OL}		0.8	V
$V_{OL(V)}$ Quiet output, minimum dynamic V_{OL}		-0.8	V
$V_{OH(V)}$ Quiet output, minimum dynamic V_{OH}	4.4		V
$V_{IH(D)}$ High-level dynamic input voltage	3.5		V
$V_{IL(D)}$ Low-level dynamic input voltage		1.5	V

NOTE 5: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

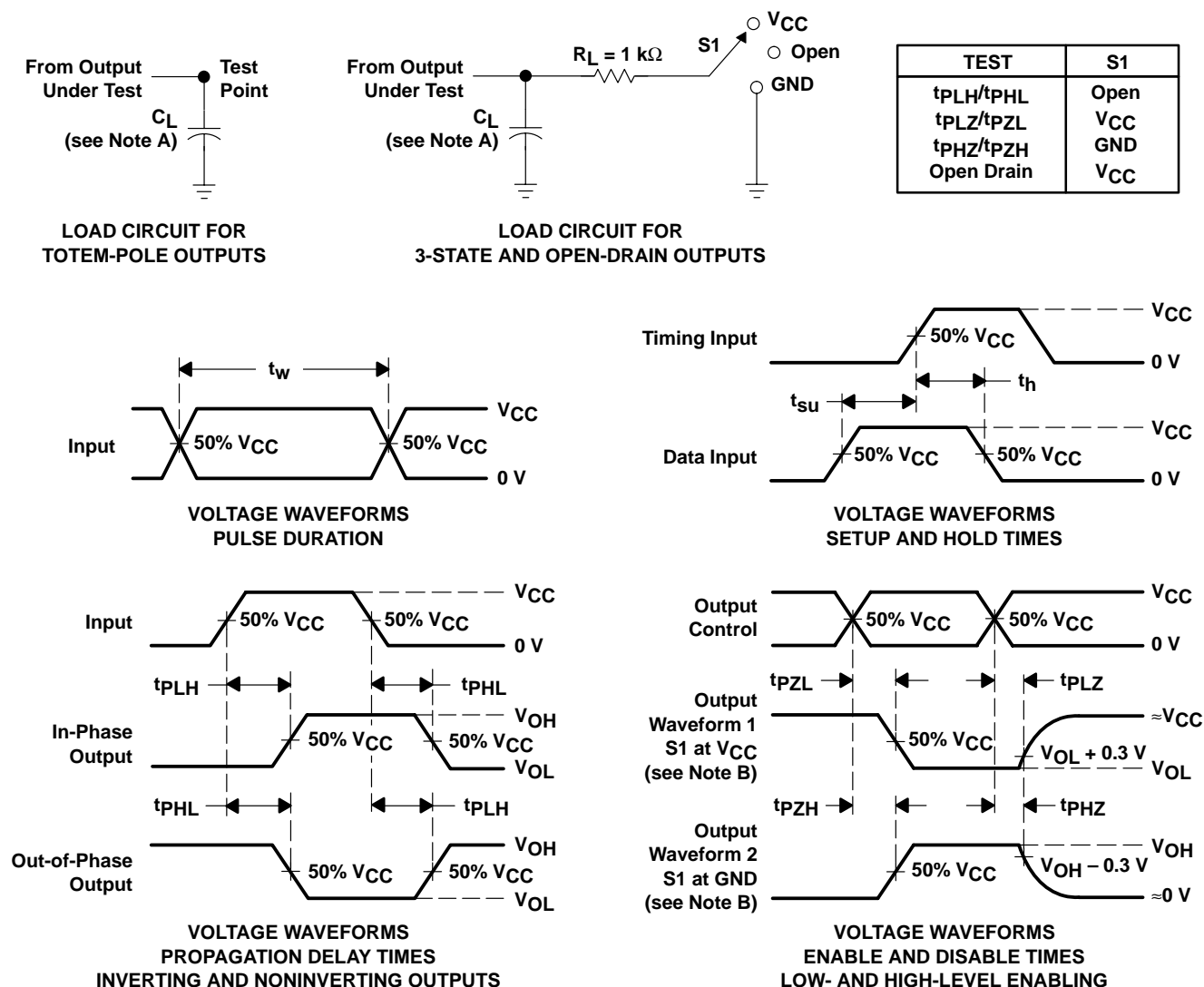
PARAMETER	TEST CONDITIONS	TYP	UNIT
C_{pd} Power dissipation capacitance	No load, $f = 1\text{ MHz}$	14	pF



SN54AHC125, SN74AHC125 QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

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PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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